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# The Effect of Polymer Molecular Weight on the Performance of PTB7-Th:O-IDTBR Non-Fullerene Organic Solar Cells

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### **Photovoltaic Performance**



**Figure S1.** Performance analysis of PTB7-Th:O-IDTBR solar cells with a different molecular weight of PTB7-Th over ten photovoltaic devices presented as box plot diagram for the characteristic photovoltaic parameters ( $V_{OC}$ ,  $J_{SC}$ , FF, PCE). The horizontal lines denote the 25<sup>th</sup>, 50<sup>th</sup>, and 75<sup>th</sup> percentiles. The whiskers are given by the 5<sup>th</sup> and 95<sup>th</sup> percentile values. The highest and the lowest values observed are denoted with a cross, while the mean average values are represented as an empty square.



**Figure S2.** Current density–voltage (J-V) curves of PTB7-Th:O-IDTBR solar cells with a different molecular weight of PTB7-Th under illumination. The J-V curves were obtained after light soaking treatment for 0 min, 5 min and 10 min under continuous illumination with a Dedolight DLH400D xenon lamp (1000 W m<sup>-2</sup>, AM 1.5 G).



**Figure S3.** Normalized UV-Vis absorption spectra of (A) PTB7-Th solutions in chloroform and (B) PTB7-Th thin films deposited from *ortho*-dichlorobenzene with a different molecular weight.

Table S1. Optical properties of PTB7-Th with different molecular weight

Molecular Weight	λ <sub>max,sol</sub>	λ <sub>max,film</sub>	$\alpha$ at $\lambda_{max}$	λ <sub>onset,film</sub>	$E_{ m g}^{ m opt \ a)}$
	[nm]	[nm]	$[10^5 \text{ cm}^{-1}]$	[nm]	[eV]
50 kDa	697	706±0	1.77±0.02	781±2	1.59±0.00
100 kDa	697	706±1	1.86±0.16	781±2	1.59±0.00
200 kDa	699	703±2	1.56±0.11	781±4	1.59±0.01
300 kDa	699	703±1	1.54±0.10	781±3	1.59±0.01

a) The optical bandgap was determined from the onset of the thin film absorption spectra. Values for thin films were averaged over three samples.



**Figure S4.** Normalized UV-Vis absorption spectra of a solution (in chloroform) and a thin film of PTB7-Th (200 kDa).

The difference in molecular weight has a negligible impact on the absorption properties of solution (in chloroform) and thin film samples (Figure S3). It can be therefore concluded that the effective conjugation length of PTB7-Th is already saturated, which is suggested to be below 50 kDa.<sup>[1,2]</sup> Comparing the absorption spectra of solution and thin film samples, a marginal bathochromic shift of the absorption maximum (4–9 nm) is observable, as reported previously (Figure S4).<sup>[3]</sup> This is considerably different to homopolymers like P3HT, where absorption spectra are typically red-shifted from solution to solid-state.<sup>[4]</sup>



**Figure S5.** (A) A typical transconductance measurement of a PTB7-Th thin film (200 kDa) using a  $V_{\rm DS}$  of -40 V. Squares represent a decreasing  $V_{\rm GS}$  sweep from 40 V to -40 V, while circles represent an increasing  $V_{\rm GS}$  sweep from -40 V to 40 V. Dotted lines represent a standard transistor equation of  $I_{\rm DS}-V_{\rm GS}$  dependence in the saturation regime. (B) Field-effect hole mobility of PTB7-Th thin films with different molecular weight calculated from the saturation transconductance curves. Box plots represent the field-effect hole mobility values extracted from measurements with an increasing  $V_{\rm GS}$  voltage (red) and a decreasing  $V_{\rm GS}$  voltage (blue). (C) Typical output characteristics of PTB7-Th thin films with different molecular weight at a  $V_{\rm GS}$  of -40 V. The results correspond to 20 µm OFETs.

#### Details of the calculation of the Arrhenius-type activation energy $(E_a)$

The symbols in Fig. 3B represent the field-effect mobilities of OFETs as a function of 1000/T, where *T* is the temperature in K. The dotted lines represent the Arrhenius-type dependence

$$\log\left(\mu/\mu_0\right) = -E_a/k_{\rm B}T\tag{1}$$

where  $E_a$  is the activation energy,  $k_B$  is the Boltzmann constant, *T* is the temperature,  $\mu_0$  is the field-effect mobility at infinite temperature and  $\mu$  is the field-effect mobility. The field-effect mobility was calculated using standard field-effect transistor equations from the  $I_{DS}-V_{GS}$  graphs in the saturation regime as explained in the experimental section. For temperature-dependent field-effect mobility measurements, the device characteristics were measured by sweeping the temperature from  $-20 \text{ }^{\circ}\text{C}$  to  $60 \text{ }^{\circ}\text{C}$  and back from 50  $^{\circ}\text{C}$  to  $-10 \text{ }^{\circ}\text{C}$  using a temperature step of 20  $^{\circ}\text{C}$  with the device temperature being controlling using a Peltier element.

We note that the logarithm of the measured mobility exhibits a linear dependence on 1/T for temperatures above 20 °C, as demonstrated in Fig. 3B. Therefore, the mobility dependence on *T* above 20 °C was analyzed using Eq.(1). Hence, the activation energy (*E*<sub>a</sub>) was estimated using the least-square minimization method of the difference between the logarithm of the measured mobility and the right side of Eq.(1), as presented in Fig. 3B. Consequently,  $\mu_0$  and *E*<sub>a</sub> were estimated as the »best-fit« parameters of the Eq.(1) for the temperature above 20 °C. The values of the model parameters are summarized in Table S2.

Molecu	ılar Weight	$\mu_0 \ [\mathrm{cm}^2 \ \mathrm{V}^{-1} \ \mathrm{s}^{-1}]$	E <sub>a</sub> [meV]
5	0 kDa	1.7±0.4	165±6
1(	00 kDa	1.6±0.8	156±11
20	00 kDa	0.29±0.03	98±2
30	00 kDa	1.8±0.5	142±7

**Table S2**. Values for  $\mu_0$  and  $E_a$  determined as described above

## Grazing Incidence X-Ray Diffraction

**Table S3.** X-ray diffraction peak positions of the (010) reflection and the corresponding *d*-spacing distances for PTB7-Th with different molecular weights deposited from *ortho*-dichlorobenzene solutions via spin coating

 Molecular Weight	2 <i>θ</i> [deg]	<i>d</i> [Å]
 50 kDa	22.12	4.02
100 kDa	22.43	3.96
200 kDa	22.06	4.03
300 kDa	22.12	4.02

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